Comparative Study of SnS_xSe_{2-x} alloys by High Pressure Raman Spectroscopy

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In this work, the hydrostatic pressure response of the phonon modes of ternary SnS_xSe_{2-x} (*x*=0.6, 0.8, 1) alloys has been studied by means of Raman spectroscopy. High pressure (up to 8 GPa) was generated using a gas membrane-type diamond anvil cell. Owing to the two-mode behaviour of the E_g and A_{1g} modes in the ternary dichalcogenide alloys investigated [1], four Raman bands are observed at ambient conditions and the frequency evolution of three of them { $E_g(SnSe_2-like)$, $A_{1g}(SnSe_2-like)$ and $A_{1g}(SnS_2-like)$ } was followed with pressure. Upon pressure application, all Raman peaks monotonically shift to higher frequencies due to the volume reduction and the bond strengthening (Figure 1).



Figure 1: Pressure evolution of the frequencies of the clearly resolved Raman peaks in the SnS_xSe_{2-x} alloys. Open (closed) circles correspond to pressure increase (decrease).

The pressure coefficient of the $A_{1g}(SnS_2-like)$ peak frequency increases gradually from 3.60 to 3.93 cm⁻¹GPa⁻¹ with increasing S content, *x*. These values are compatible with those reported in the literature for the binary SnS₂[2]. At the same time, the pressure coefficient of the $A_{1g}(SnSe_2-like)$ peak frequency decreases from 3.08 to 2.72 cm⁻¹GPa⁻¹ with *x*, being always larger than that observed for the binary SnSe₂ [2]. Furthermore, contrary to the strong covalent bonding along the *a*-axis compared to the weak van der Waals interactions along the *c*-axis, the in-plane E_g(SnSe₂-like) mode exhibits larger pressure coefficient than those of the A_{1g} modes along the *c*-axis in all the studied alloys. We also extracted the Grüneisen parameters for the A_{1g}(SnS₂-like): 0.35, 0.34, 0.36 and the A_{1g} (SnSe₂-like) mode: 0.44, 0.41, 0.37 for *x*=0.6, 0.8 and 1, respectively. These values indicate the stronger Sn-S interaction along the *c*-axis compared to the Sn-Se one in the ternary alloys, in agreement with the existing X-ray diffraction (XRD) data in the literature [3].

References

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